NSN 5961-01-294-5731

Thyristor Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-294-5731 **Inclosure Material:** Plastic **Overall Length:** Between 14.23 millimeters and 16.51 millimeters **Terminal Length:** Between 12.7 millimeters and 14.73 millimeters **Overall Height:** Between 3.56 millimeters and 4.82 millimeters **Overall Width:** Between 9.66 millimeters and 10.66 millimeters Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-220ab **Mounting Method: Terminal Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 200.0 repetitive peak off-state voltage **Current Rating Per Characteristic:** 10.00 amperes forward current, total rms horsepower metric and 100.00 amperes peak forward surge current nanoamperes **Maximum Operating Tempurature Per Measurement Point:** 129.0 degrees celsius junction **Terminal Type And Quantity:** 3 printed circuit Shelf Life: N/a **Unit Of Measure:** Demilitarization: No Fiig: A110a0